



PDS835L

8A LOW VF SCHOTTKY BARRIER RECTIFIER POWERDI®

Features

- Guard Ring Die Construction for Transient Protection
- Low Forward Voltage Drop
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications
- High Forward Surge Current Capability
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: POWERDI5
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper leadframe.
 Solderable per MIL-STD-202, Method 208 ³
- Polarity: See Diagram
- Weight: 0.094 grams (approximate)

POWERDI5





Top View Bottom View

RIGHT PIN O BOTTOMSIDE HEAT SINK

Note: Pins Left & Right must be electrically connected at the printed circuit board.

Ordering Information (Note 4)

ĺ	Part Number	Case	Packaging
	PDS835L-13	POWERDI5	5000/Tape & Reel
	PDS835L-7	POWERDI5	1500/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com.

Marking Information



S835L = Product type marking code

| Second Product type marking code
| Second Product Second Pr



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RM} V _{RWM} V _R	35	V
RMS Reverse Voltage	V _{R(RMS)}	25	V
Average Rectified Output Current (See also figure 5)	Ιο	8	A
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	120	А

Thermal Characteristics

Characteristic	Symbol	Тур	Max	Unit
Thermal Resistance Junction to Soldering Point	$R_{ heta JS}$	_	3.0	°C/W
Thermal Resistance Junction to Ambient Air (Note 5) T _A = +25°C	$R_{ heta JA}$	100	_	°C/W
Thermal Resistance Junction to Ambient Air (Note 6) T _A = +25°C	$R_{ hetaJA}$	65	_	°C/W
Thermal Resistance Junction to Ambient Air (Note 7) T _A = +25°C	$R_{ hetaJA}$	45	_	°C/W
Operating Temperature Range	TJ	-65 to +125		°C
Storage Temperature Range	T_{STG}	-65 to +150		°C

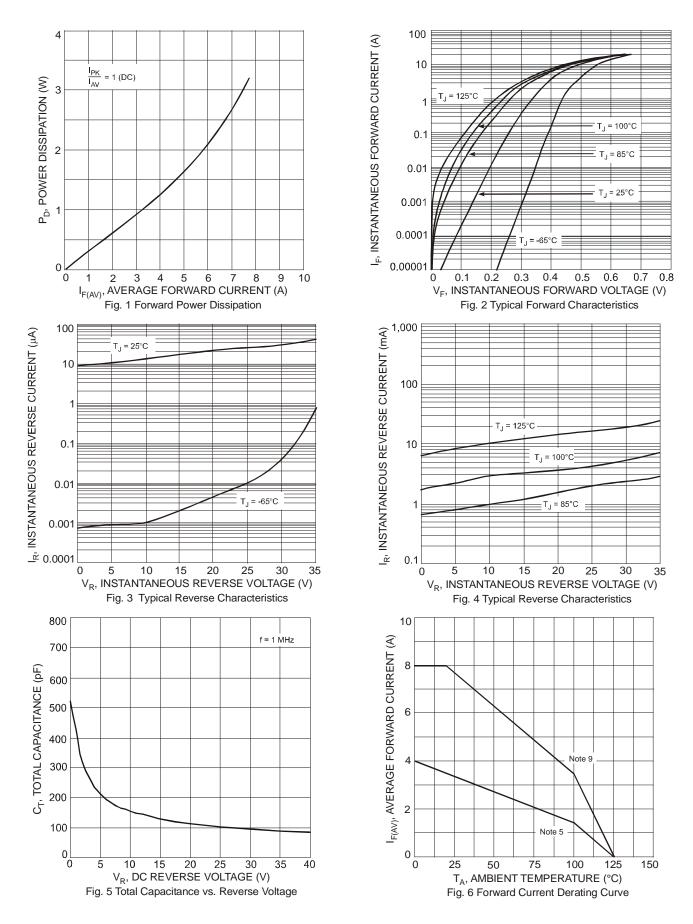
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 8)	$V_{(BR)R}$	35		_	V	$I_R = 1mA$
Forward Voltage	V _F	_	0.46	0.51 0.41		$I_F = 8A, T_S = +25$ °C $I_F = 8A, T_S = +125$ °C
Reverse Leakage Current (Note 8)	I _R		0.05 7	1.4 35	mA	$T_S = +25$ °C, $V_R = 35$ V $T_S = +100$ °C, $V_R = 35$ V

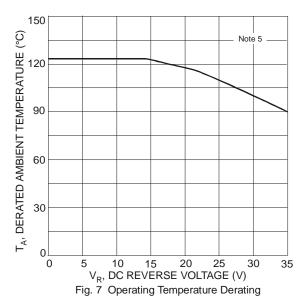
Notes:

- 5. FR-4 PCB, 2 oz. Copper, minimum recommended pad layout per http://www.diodes.com
- Polymide PCB, 2 oz. Copper, minimum recommended pad layout per http://www.diodes.com.
 Polymide PCB, 2 oz. Copper. Cathode pad dimensions 9.4mm x 7.2mm. Anode pad dimensions 2.7mm x 1.6mm.
- 8. Short duration pulse test used to minimize self-heating effect.





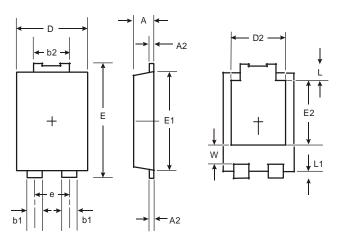




Notes: 9. Polymide PCB, 2 oz. Copper. Cathode pad dimensions 18.8mm x 14.4mm. Anode pad dimensions 5.6mm x 3.0mm.

Package Outline Dimensions

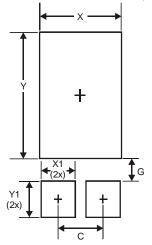
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



POWERDI5				
Dim	Min	Max		
Α	1.05	1.15		
A2	0.33	0.43		
b1	0.80	0.99		
b2	1.70	1.88		
D	4.05			
D2	3.054 Typ			
Е	E 6.40 6.0			
е	1.84 Typ			
E1	E1 5.30 5.45			
E2	E2 3.549 Typ			
L	L 0.75 0.95			
L1	1 0.50 0.65			
W	W 1.10 1.41			
All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	1.840
G	0.852
Х	3.360
X1	1.390
Y	4.860
Y1	1.400



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